FEATURES

- 8 Darlington Arrays per Package
- 500 mA Rated Collector Current (Single Output)
- Output voltage 50V
- Output Clamp Diodes
- Input Compatible with Various Types of Logic
- Relay-Driver Applications
- Input pins placed opposite to output pins to simplify layout

APPLICATION

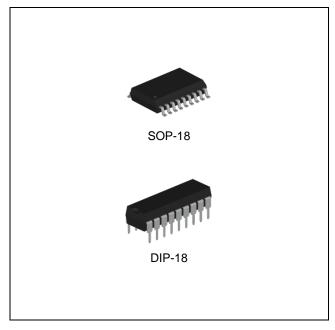
- Relay Drivers
- Stepper and DC Brushed Motor Drivers
- Lamp Drivers
- Display Drivers
- Line Drivers
- Logic Buffers

DESCRIPTION

The ULN2803A is monolithic high-voltage, high-current Darlington transistor arrays. Each consists of eight NPN Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

ABSOLUTE MAXIMUM RATINGS (Note 1)

CHARACTERISTIC	SYMBOL	MIN.	MAX.	UNIT
Output Voltage	Vo	-	50	V
Input Voltage (Note 2)	VI	-	30	V
Peak Collector Current	Ι _C	-	500	mA
Output Clamp Current	I _{OK}	-	500	mA
Total Emitter-Terminal Current	Ι _Ε	-	2.5	А
Maximum Junction Temperature	TJ	-	150	°C



ORDERING INFORMATION

Device	Package
ULN2803AD	SOP-18
ULN2803AN	DIP-18

ULN2803A

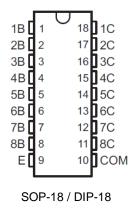
RECOMMENDED OPERATIONG CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	MAX.	UNIT
Output Voltage	Vo	-	50	V
Junction Temperature	TJ	-40	125	°C
Operating Free-Air Temperature Range	T _A	-40	85	°C

ORDERING INFORMATION

Package	Order No.	Description	Package Marking	Status	
SOP-18	ULN2803AD	8-Digit Darlington Current Driver	ULN2803A	Active	
DIP-18	ULN2803AN	8-Digit Darlington Current Driver	ULN2803A	Active	

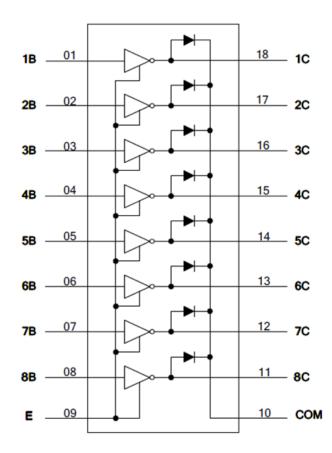
PIN CONFIGURATION



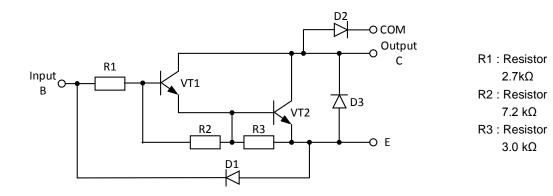
PIN DESCRIPTION

Pin No.		Pin Name	Die Eventier			
SOP-18	DIP-18	Pin Name	Pin Function			
1	1	1B				
2	2	2B				
3	3	3B				
4	4	4B	Channel 1 through 9 Darlington Roos Input			
5	5	5B	Channel 1 through 8 Darlington Base Input			
6	6	6B				
7	7	7B				
8	8	8B				
9	9	E	Common Cathode Node for Flyback Diodes			
10	10	СОМ	Common Emitter shared by All Channels			
11	11	8C				
12	12	7C				
13	13	6C				
14	14	5C	Channel 1 through 8 Darlington Collector Output			
15	15	4C				
16	16	3C				
17	17	2C				
18	18	1C				

PIN CONNECTION DIAGRAM



BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS (Note 3)

Limits in standard typeface are for $T_J=25^{\circ}C$, unless otherwise specified.

PARAMETER	SYMBOL	TEST FIGURE	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
ON-State Input Voltage	V _{I(ON)}	Fig.1.	V _{CE} =2V	I _C =200mA	-	-	2.4	V
				I _C =250mA	-	-	2.7	
				I _C =300mA	-	-	3.0	
Collector-Emitter Saturation Voltage		Fig. 2.	I _I =250μA, I _C =100mA		-	0.9	1.1	V
	V _{CE(SAT)}		I _I =350μA, I _C =200mA		-	1.0	1.3	
			I _I =500μA, I _C =350mA		-	1.2	1.6	
	ICEX	Fig. 3. Fig. 4.	V _{CE} =50V,	I _I =0mA	-	-	50	
Output Leakage Current			V _{CE} =50V, T _A =85°C	I _I =0mA	-	-	100	μA
				V _I =1V	-	-	500	
Clamp Forward Voltage	VF	Fig. 5.	I _F =350mA		-	1.7	2	V
Off-State Input Current	I _{I(OFF)}	Fig. 6.	V _{CE} =50V, I _C =500µA, T _A =85°C		50	65	-	μA
Input Current	I _{I(ON)}	Fig. 7.	V _I =3.85V		-	-	1.35	mA
Clamp Diode Leakage Current	I _R Fig		V _R =50V		-	-	50	
		Fig. 8.	V _R =50V, T _A =85°C		-	-	100	μA
Turn-On Propagation Delay Time	t _{PLH}	-	$0.5V_{I}$ to $0.5V_{O}$		-	0.25	1	
Turn-Off Propagation Delay Time	t _{PHL}	-	$0.5V_{\rm l}$ to $0.5V_{\rm O}$		-	0.25	1	μs

Note 1. Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Note 2. All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

Note 3. The device is not guaranteed to function outside its operating ratings.

PARAMETER MEASUREMENT INFORMATION

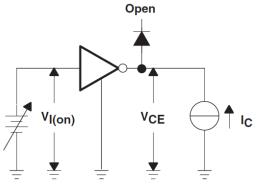


Fig. 1. ON-State Input Voltage Test Circuit

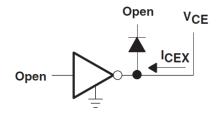


Fig. 3. Output Leakage Current Test Circuit

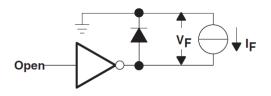


Fig. 5. Clamp Forward Voltage Test Circuit

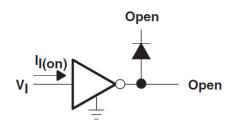


Fig. 7. Input Current Test Circuit

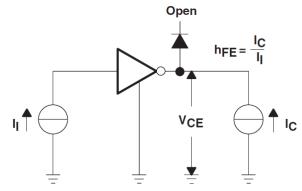


Fig. 2. Collector-Emitter Saturation Voltage Test Circuit

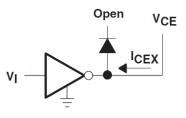


Fig. 4. Output Leakage Current Test Circuit

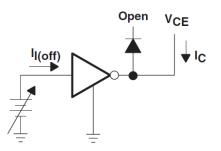


Fig. 6. Off-State Input Current Test Circuit

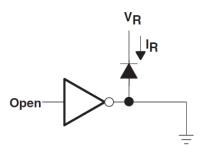
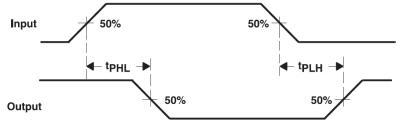


Fig. 8. Clamp Diode Leakage Current Test Circuit



VOLTAGE WAVEFORMS

Fig. 9. Propagation Delay Time Waveform

APPLICATION INFORMATION

T.B.D.

TYPICAL OPERATING CHARACTERISTICS

T.B.D.

REVISION NOTICE

The description in this datasheet is subject to change without any notice to describe its electrical characteristics properly.

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